PIN CONFIGURATION

			1
1DIR	1	48	10E
1B1	2	47	1A1
1B2	3	46	1A2
GND	4	45	GND
1B3	5	44	1A3
1B4	6	43	1A4
Vcc	7	42	Vcc
1B5	8	41	1A5
1B6	9	40	1A6
GND	10	39	GND
1B7	11	38	1A7
1B8	12	37	1A8
2B1	13	36	2A1
2B2	14	35	2A2
GND	15	34	GND
2B3	16	33	2A3
2B4	17	32	2A4
Vcc	18	31	Vcc
2B5	19	30	2A5
2B6	20	29	2A6
GND	21	28	GND
2B7	22	27	2A7
2B8	23	26	2A8
2DIR	24	25	20E

TSSOP TOP VIEW

INDUSTRIAL TEMPERATURE RANGE

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	DC Output Current	-50 to +50	mA
Ік	Continuous Clamp Current, VI < 0 or VI > Vcc	±50	mA
Іок	Continuous Clamp Current, Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	5	7	pF
Соит	Output Capacitance	Vout = 0V	7	9	pF
Соит	I/O Port Capacitance	VIN = 0V	7	9	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description	
xOE Output Enable Inputs (Active LOW)		
xDIR	DIR Direction Control Inputs	
xAx Side A Inputs or 3-State Outputs		
хВх	Side B Inputs or 3-State Outputs	

FUNCTION TABLE (EACH 8-BIT SECTION)(1)

Inputs		
xOE	xDIR	Outputs
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	Х	Z

NOTE:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Condition: TA = -40° C to $+85^{\circ}$ C

Symbol	Parameter	Test Co	onditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	-	—	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		-	-	0.7	V
		Vcc = 2.7V to 3.6V		—	—	0.8	
Ін	Input HIGH Current	Vcc = 3.6V	VI = VCC	_	-	±5	μA
lıL	Input LOW Current	Vcc = 3.6V	VI = GND	-	-	±5	μA
Іоzн	High Impedance Output Current	Vcc = 3.6V	Vo = Vcc	_	_	±10	μA
Iozl	(3-State Output pins)		Vo = GND		-	±10	
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		-	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		-	100	_	mV
ІССL ІССН ІССZ	Quiescent Power Supply Current	Vcc = 3.6V Vin = GND or Vcc		-	0.1	40	μA
Δlcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other	inputs at Vcc or GND	-	-	750	μA

NOTE:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	TestC	Test Conditions ⁽¹⁾		Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Iон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = – 6mA	2	_	
		Vcc = 2.3V	Iон = – 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V		2.4	_	
		Vcc = 3V	Iон = – 24mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V
		Vcc = 2.3V	IOL = 6mA	_	0.4	
			IOL = 12mA	_	0.7	
		Vcc = 2.7V	IOL = 12mA	_	0.4	
		Vcc = 3V	IOL = 24mA	_	0.55	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to + 85°C.

OPERATING CHARACTERISTICS, TA = 25°C

			Vcc = 2.5V ± 0.2V	$Vcc = 3.3V \pm 0.3V$	
Symbol	Parameter	Test Conditions	Typical	Typical	Unit
Cpd	Power Dissipation Capacitance Outputs enabled	CL = 0pF, f = 10Mhz	22	29	pF
Cpd	Power Dissipation Capacitance Outputs disabled		4	5	

SWITCHING CHARACTERISTICS(1)

		Vcc = 2.	5V ± 0.2V	Vcc	= 2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t PLH	Propagation Delay	1	3.7	—	3.6	1	3	ns
t PHL	xAx to xBx or xBx to xAx							
tрzн	Output Enable Time	1	5.7	—	5.4	1	4.4	ns
tPZL	xOE to xAx or xBx							
tphz	Output Disable Time	1	5.2	—	4.6	1	4.1	ns
tPLZ	xOE to xAx or xBx							
tsk(0)	Output Skew ⁽²⁾	_	_	_	_	_	500	ps

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = -40° C to $+85^{\circ}$ C.

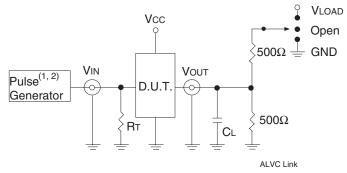
2. Skew between any two outputs of the same package and switching in the same direction.

IDT74ALVC16245 3.3V CMOS 16-BIT BUS TRANSCIEVER WITH 3-STATE OUTPUTS

INDUSTRIAL TEMPERATURE RANGE

TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽¹⁾ =2.7V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
Vload	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vτ	1.5	1.5	Vcc/2	V
Vlz	300	300	150	mV
Vhz	300	300	150	mV
Cl	50	50	30	pF



Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

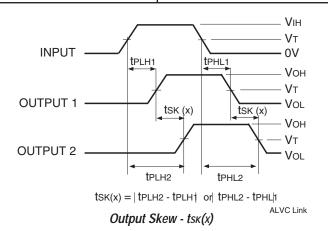
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns. 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

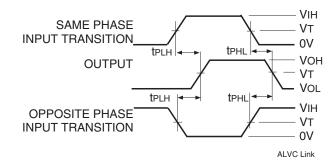
Test	Switch
Open Drain Disable Low Enable Low	Vload
Disable High Enable High	GND
All Other Tests	Open



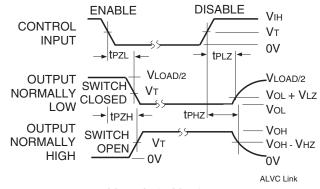
NOTES:

1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.

2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



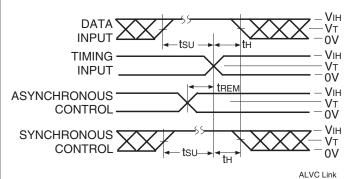




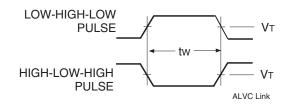
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



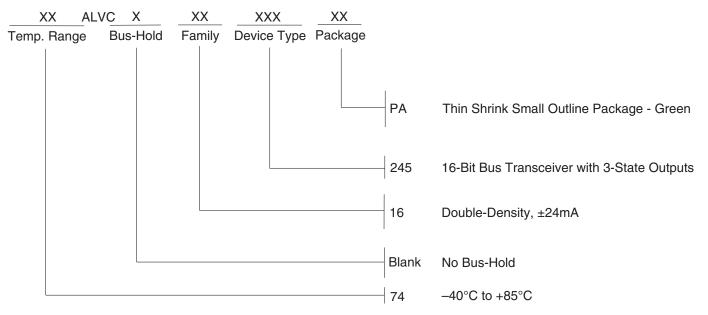
Set-up, Hold, and Release Times



Pulse Width

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ORDERING INFORMATION



INDUSTRIALTEMPERATURERANGE

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